

# BC856ALT1G Series

## General Purpose Transistors

### PNP Silicon

#### Features

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BC856 BC857 BC858, BC859	$V_{CEO}$	-65 -45 -30	V
Collector-Base Voltage BC856 BC857 BC858, BC859	$V_{CBO}$	-80 -50 -30	V
Emitter-Base Voltage	$V_{EBO}$	-5.0	V
Collector Current – Continuous	$I_C$	-100	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

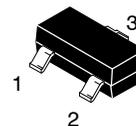
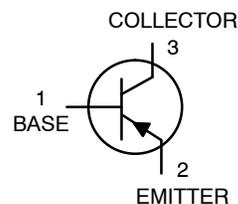
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = 1.0 x 0.75 x 0.062 in.
2. Alumina = 0.4 x 0.3 x 0.024 in 99.5% alumina.



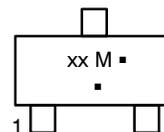
ON Semiconductor®

<http://onsemi.com>



SOT-23 (TO-236AB)  
CASE 318  
STYLE 6

#### MARKING DIAGRAM



- xx = Device Code  
xx = (Refer to page 6)
- M = Date Code\*
- = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

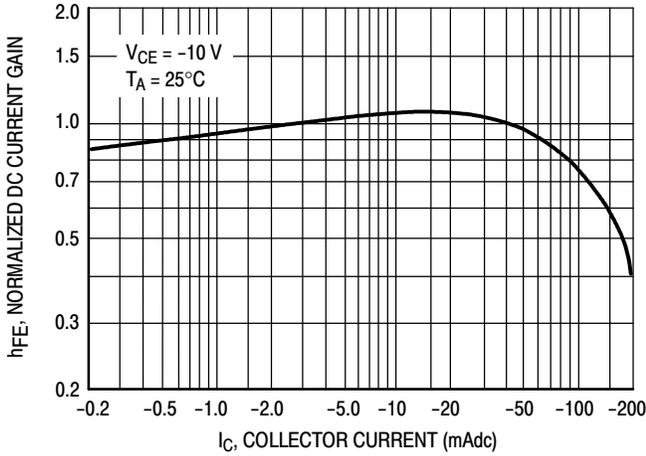
## BC856ALT1G Series

### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

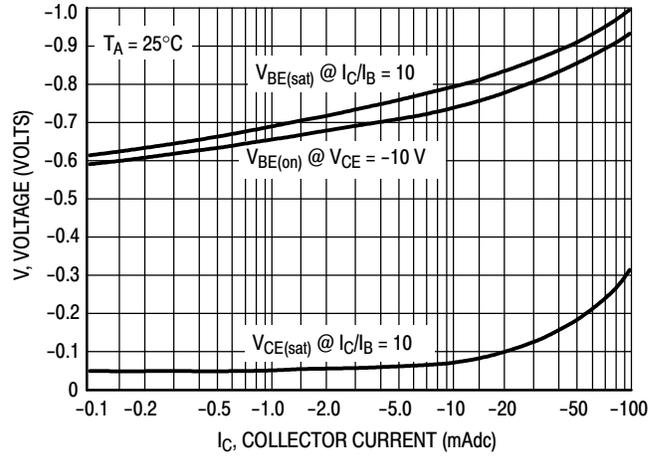
Characteristic		Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>						
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = -10 mA)	BC856 Series BC857 Series BC858, BC859 Series	V <sub>(BR)CEO</sub>	-65 -45 -30	- - -	- - -	V
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = -10 μA, V <sub>EB</sub> = 0)	BC856 Series BC857A, BC857B Only BC858, BC859 Series	V <sub>(BR)CES</sub>	-80 -50 -30	- - -	- - -	V
Collector – Base Breakdown Voltage (I <sub>C</sub> = -10 μA)	BC856 Series BC857 Series BC858, BC859 Series	V <sub>(BR)CBO</sub>	-80 -50 -30	- - -	- - -	V
Emitter – Base Breakdown Voltage (I <sub>E</sub> = -1.0 μA)	BC856 Series BC857 Series BC858, BC859 Series	V <sub>(BR)EBO</sub>	-5.0 -5.0 -5.0	- - -	- - -	V
Collector Cutoff Current (V <sub>CB</sub> = -30 V) (V <sub>CB</sub> = -30 V, T <sub>A</sub> = 150°C)		I <sub>CBO</sub>	- -	- -	-15 -4.0	nA μA
<b>ON CHARACTERISTICS</b>						
DC Current Gain (I <sub>C</sub> = -10 μA, V <sub>CE</sub> = -5.0 V)	BC856A, BC857A, BC858A BC856B, BC857B, BC858B BC857C, BC858C	h <sub>FE</sub>	- - -	90 150 270	- - -	-
(I <sub>C</sub> = -2.0 mA, V <sub>CE</sub> = -5.0 V)	BC856A, BC857A, BC858A BC856B, BC857B, BC858B, BC859B BC857C, BC858C, BC859C		125 220 420	180 290 520	250 475 800	
Collector – Emitter Saturation Voltage (I <sub>C</sub> = -10 mA, I <sub>B</sub> = -0.5 mA) (I <sub>C</sub> = -100 mA, I <sub>B</sub> = -5.0 mA)		V <sub>CE(sat)</sub>	- -	- -	-0.3 -0.65	V
Base – Emitter Saturation Voltage (I <sub>C</sub> = -10 mA, I <sub>B</sub> = -0.5 mA) (I <sub>C</sub> = -100 mA, I <sub>B</sub> = -5.0 mA)		V <sub>BE(sat)</sub>	- -	-0.7 -0.9	- -	V
Base – Emitter On Voltage (I <sub>C</sub> = -2.0 mA, V <sub>CE</sub> = -5.0 V) (I <sub>C</sub> = -10 mA, V <sub>CE</sub> = -5.0 V)		V <sub>BE(on)</sub>	-0.6 -	- -	-0.75 -0.82	V
<b>SMALL-SIGNAL CHARACTERISTICS</b>						
Current – Gain – Bandwidth Product (I <sub>C</sub> = -10 mA, V <sub>CE</sub> = -5.0 Vdc, f = 100 MHz)		f <sub>T</sub>	100	-	-	MHz
Output Capacitance (V <sub>CB</sub> = -10 V, f = 1.0 MHz)		C <sub>ob</sub>	-	-	4.5	pF
Noise Figure (I <sub>C</sub> = -0.2 mA, V <sub>CE</sub> = -5.0 Vdc, R <sub>S</sub> = 2.0 kΩ, f = 1.0 kHz, BW = 200 Hz)	BC856, BC857, BC858 Series BC859 Series	NF	- -	- -	10 4.0	dB

# BC856ALT1G Series

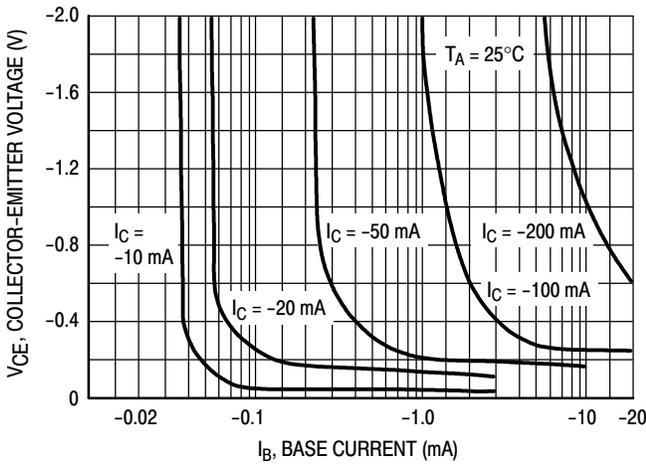
## BC857/BC858/BC859



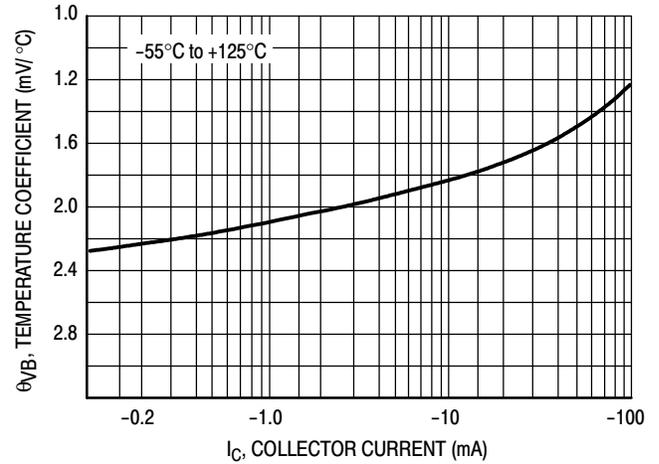
**Figure 1. Normalized DC Current Gain**



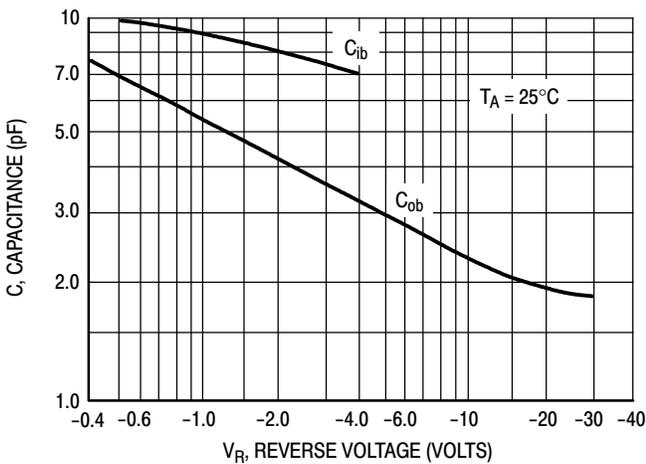
**Figure 2. "Saturation" and "On" Voltages**



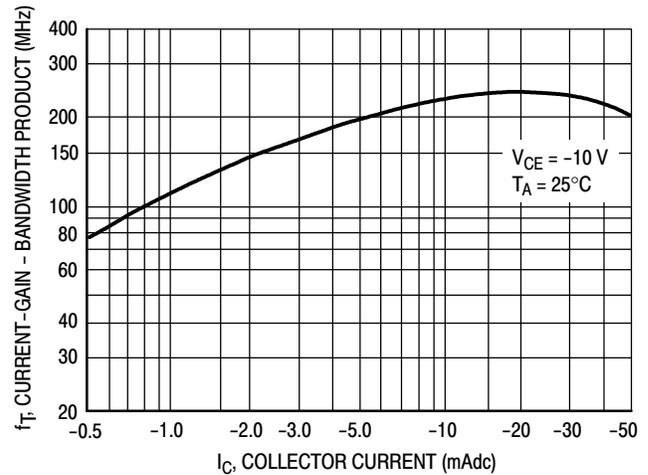
**Figure 3. Collector Saturation Region**



**Figure 4. Base-Emitter Temperature Coefficient**



**Figure 5. Capacitances**



**Figure 6. Current-Gain - Bandwidth Product**

# BC856ALT1G Series

## BC856

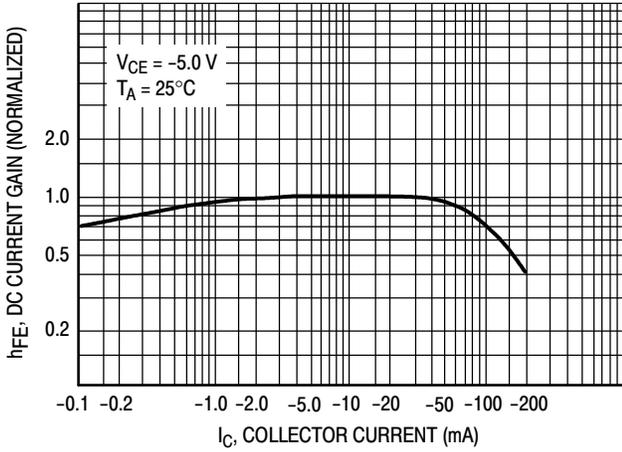


Figure 7. DC Current Gain

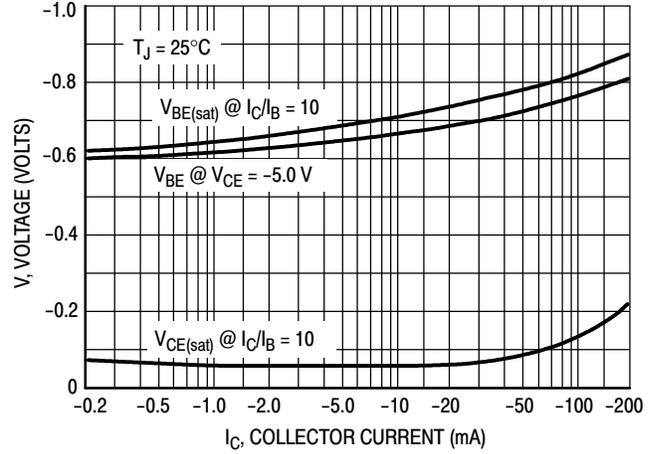


Figure 8. "On" Voltage

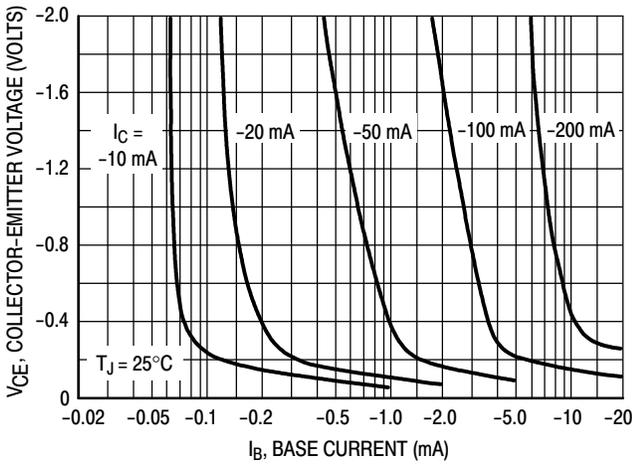


Figure 9. Collector Saturation Region

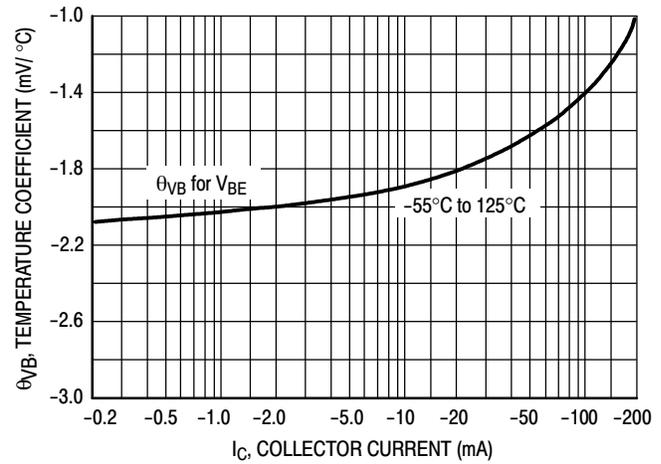


Figure 10. Base-Emitter Temperature Coefficient

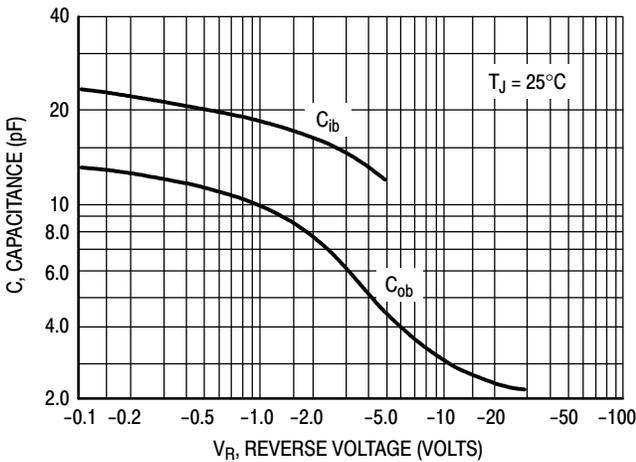


Figure 11. Capacitance

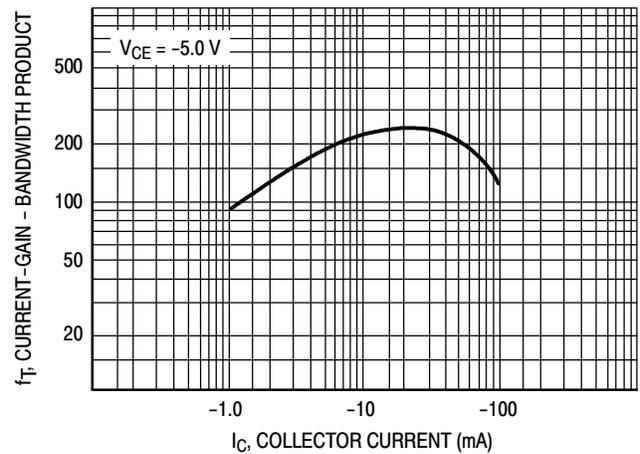


Figure 12. Current-Gain - Bandwidth Product

# BC856ALT1G Series

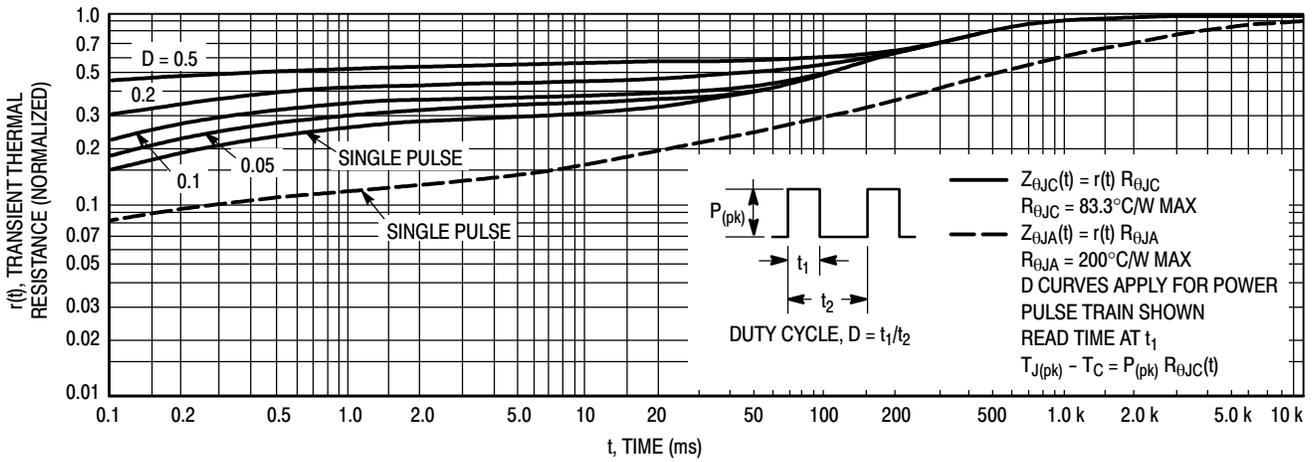


Figure 13. Thermal Response

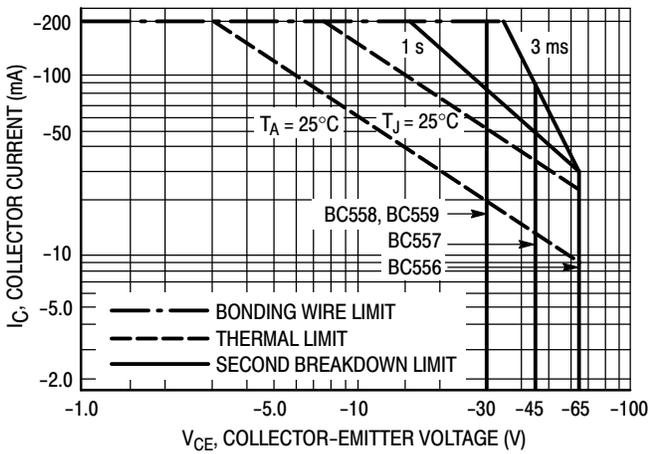


Figure 14. Active Region Safe Operating Area

The safe operating area curves indicate  $I_C$ - $V_{CE}$  limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon  $T_{J(pk)} = 150^\circ\text{C}$ ;  $T_C$  or  $T_A$  is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided  $T_{J(pk)} \leq 150^\circ\text{C}$ .  $T_{J(pk)}$  may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

## BC856ALT1G Series

### ORDERING INFORMATION

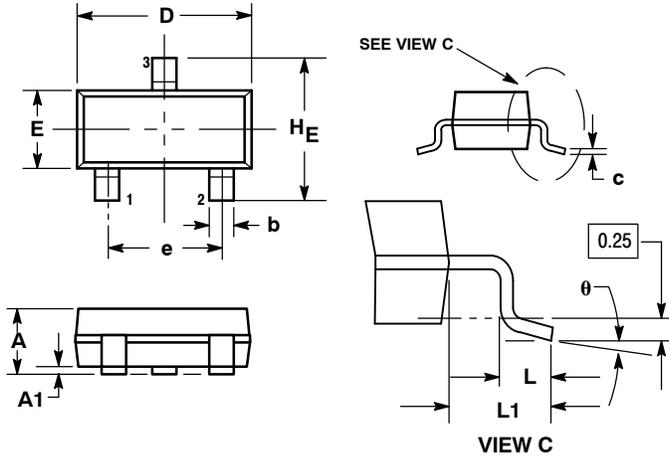
Device	Marking	Package	Shipping <sup>†</sup>
BC856ALT1G	3A	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC856ALT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC856BLT1G	3B	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC856BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC857ALT1G	3E	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC857BLT1G	3F	SOT-23 (Pb-Free)	
BC857BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC857CLT1G	3G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC857CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC858ALT1G	3J	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC858BLT1G	3K	SOT-23 (Pb-Free)	
BC858BLT3G	3L	SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC858CLT1G		SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC858CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC859BLT1G	4B	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC859BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel
BC859CLT1G	4C	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BC859CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# BC856ALT1G Series

## PACKAGE DIMENSIONS

SOT-23 (TO-236)  
CASE 318-08  
ISSUE AN

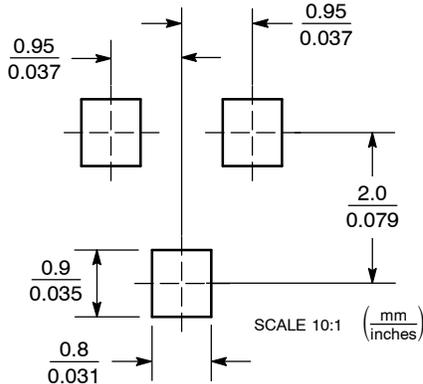


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
  4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

- STYLE 6:  
PIN 1. BASE  
2. EMITTER  
3. COLLECTOR

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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